

AMENDMENTS TO THE CLAIMS

The following listing of claims will replace all prior versions and listings of claims in the application.

1. - 34. Cancelled

35. (Currently Amended) A method of forming a silica film coated on a substrate including the steps of:

 producing a silica precursor ~~formulation~~solution having a water content of no more than 5% by volume by ~~adding~~dissolving silicic acid tetramethyl ester homopolymer ~~to~~in a solvent;

 coating a substrate with the silica precursor ~~formulation~~solution; and

 curing the silica precursor ~~formulation~~solution onto the substrate in a vaporous ammoniacal environment.

36. (Previously Presented) The method of claim 35 wherein the solvent is alcohol or an alcohol-aqueous solution.

37. (Currently Amended) The method of claim 35 wherein the silica precursor ~~formulation~~solution contains an amount of tetramethoxysilane.

38. (Currently Amended) The method of claim 35 wherein the silica precursor ~~formulation-solution~~ is formed by adding methyl-silicate-51 (MS-51), comprising greater than ~~or equal to 94%~~ and less than ~~or equal to 99.8 %~~ silicic acid tetramethyl ester homopolymer by volume, greater than ~~or equal to 0.1%~~ and less than ~~or equal to 3%~~ tetramethoxysilane by volume and greater than ~~or equal to 0.1 %~~ and less than ~~or equal to 3%~~ methanol by volume, to the solvent.

39. (Currently Amended) The method of claim 38 wherein the silica precursor ~~formulation-solution~~ comprises about 0.2-100 parts alcohol by volume and 0.01-1 parts water by volume for each part of MS-51.

40. (Currently Amended) The method of claim 39 wherein the silica precursor ~~formulation-solution~~ comprises about 0.2-5 parts alcohol by volume and 0.01-0.1 parts water by volume for each part of MS-51.

41. (Currently Amended) The method of claim 40 wherein the ratio of reagents in the silica precursor ~~formulation-solution~~ is 1.0 part MS-51: 0.1 parts water: 10.0 parts alcohol by volume.

42. (Previously Presented) The method of claim 35 wherein the coating is performed by spin coating or dipping.

43. (Previously Presented) The method of claim 35 wherein the coating further includes allowing the coating to settle before curing.
44. (Previously Presented) The method of claim 35 wherein the curing is carried out by placing the coated substrate in a closed ammoniacal environment.
45. (Previously Presented) The method of claim 44 wherein the ammoniacal environment contains water, ammonia and alcohol.
46. (Currently Amended) The method of claim 45 wherein the solvent used in the formation of the silica precursor solution is an alcohol, and the alcohol contained in the ammoniacal environment is the same alcohol as used in the formation of the silica precursor solution.
47. (Previously Presented) The method of claim 35 further including controlling the solvent content to control characteristics of the silica film.
48. (Previously Presented) The method of claim 45 further including controlling the alcohol content in the ammoniacal environment to control characteristics of the silica film.

49. (Currently Amended) The method of claim 35 further including controlling a pore size of the silica film by controlling the solvent content and type in the silica precursor ~~formulation~~solution.

50. (Previously Presented) The method of claim 35 further including controlling a pore density of the silica film by controlling the solvent content and type in the ammoniacal environment.

51. (Currently Amended) The method of claim 46 further including controlling a porosity of the silica film by controlling the solvent content and type in the precursor ~~formulation~~solution and alcohol content and type in the ammoniacal environment.

Claims 52-57 are cancelled

58. (Withdrawn) An anti-reflection coating for a transparent substrate comprised by a silica film formed according to the method of claim 35.

59. (Cancelled)

60. (Withdrawn) An anti-scratch coating for a substrate comprised by a silica film formed according to the method of claim 35.

61. (Withdrawn) An anti-static coating for a substrate comprised by a silica film formed according to the method of claim 35.

62. (Currently Amended) A method of forming a silica film coated on a substrate including the steps of:

producing a silica precursor ~~formulation~~solution having a water content of no more than 5% by volume by ~~adding~~dissolving silicic acid tetramethyl ester homopolymer ~~to in~~ a solvent;

coating a substrate with the silica precursor ~~formulation~~solution to form a coated substrate;

placing the coated substrate in a curing chamber;

establishing equilibrium between the solvent in the silica precursor formulation solution and an internal atmosphere of the curing chamber; and

curing the silica precursor ~~formulation~~solution onto the substrate in an ammoniacal environment containing solvent by introducing ammonia vapour and water vapour into the curing chamber.

63. (Currently Amended) The method of claim 36 wherein the silica precursor ~~formulation~~solution is formed by adding methyl-silicate-51 (MS-51), comprising greater than or equal to 94% and less than or equal to 99.8% silicic acid tetramethyl ester homopolymer by volume, greater than or equal to 0.1% and less than or equal to 3% tetramethoxysilane by volume and greater than or equal to 0.1% and less than or equal to 3% methanol by volume, to the solvent.